

Reading out the state of a flux qubit by Josephson transmission line solitons

Arkady Fedorov,* Alexander Shnirman, and Gerd Schön
*Institut für Theoretische Festkörperphysik and DFG-Center for Functional Nanostructures (CFN),
 Universität Karlsruhe, D-76128 Karlsruhe, Germany*

Anna Kidiyarova-Shevchenko
Microtechnology and Nanoscience Department, Chalmers University of Technology, 412 96 Gothenburg, Sweden
 (Received 28 November 2006; revised manuscript received 2 February 2007; published 7 June 2007)

We describe the readout process of the state of a Josephson flux qubit via solitons in Josephson transmission lines (JTLs) as they are in use in the standard rapid single flux quantum technology. We consider the situation where the information about the state of the qubit is stored in the time delay of the soliton. We analyze dissipative underdamped JTLs, take into account their jitter, and provide estimates of the measuring time and efficiency of the measurement for relevant experimental parameters.

DOI: [10.1103/PhysRevB.75.224504](https://doi.org/10.1103/PhysRevB.75.224504)

PACS number(s): 03.67.Lx, 85.25.-j, 03.65.Ta

I. INTRODUCTION

The past few years have brought substantial breakthroughs in experiments with Josephson qubits, with further progress depending to a large extent on our ability to control the circuits with high precision and, at the same time, avoid decoherence. One of the promising ideas combines Josephson flux qubits with the well-developed classical rapid single flux quantum (RSFQ) technology.¹⁻³ RSFQ elements should allow for more reliable on-chip control and measurements than what can be achieved with control pulses sent over long coaxial cables. However, they have the drawback of being dissipative and thus noisy. The effect of this noise needs to be investigated, and ways need to be found to minimize it.

In this paper, we consider one of the possible elements of a RSFQ circuit, namely, a Josephson transmission line (JTL). The JTL supports propagating signals in the form of Josephson solitons (phase slips), also called fluxons. As suggested by Averin *et al.*,¹ ballistic fluxons in the JTL can be used to read out the state of a superconducting flux qubit in a setup as shown in Fig. 1. In the proposed schemes, the information about the state of a qubit is contained either in the fluxon transmission probability (transmission detection mode) or propagation time (delay time detection mode). Under certain ideal conditions, the measurement time is equal to the back-action dephasing time, which implies that the JTL can operate as an ideal detector. In this paper, we investigate the efficiency that can be achieved in the delay time detection mode. For that purpose, we evaluate the delay time in three different setups illustrated in Fig. 2: (a) when the qubit is kept away from the symmetry point all the time, (b) when the qubit is initially prepared at the symmetry point, but the approaching soliton pushes the qubit far from the symmetry point, and (c) when the qubit is near the symmetry point all the time. We analyze the relation between the delay time and the dissipation as well as the probability of errors introduced by the measurement. Finally, we compare the delay time with the characteristic time uncertainty due to jitter (thermal fluctuations) in the JTL, and we determine how many solitons are needed for a reliable measurement.

For a flux qubit operated far from the symmetry point, the eigenstates are persistent current states. The persistent cur-

rent in the qubit loop induces an external magnetic flux in the JTL, which provides a scattering potential for the fluxon and is responsible for the time delay of the fluxon propagation. The sign of the magnetic flux and the value of the delay time depend on the state of the qubit, which allows measuring its quantum state.

For a qubit prepared in one of the energy eigenstates at the symmetry point, the expectation value of the current in the loop vanishes. However, for strong qubit-JTL coupling, the fluxon shifts the working point of the qubit away from the symmetry point, and then again the qubit produces a magnetic flux in the JTL. The delay time is approximately the same as if the qubit were in a persistent current state corresponding to the induced shift.

For weak qubit-JTL coupling, a fluxon shifts the working point of the qubit only slightly around the symmetry point. For this case, we demonstrate that the qubit introduces an effective inductance to the JTL with sign depending on the qubit eigenstate. The local change of the inductance of the JTL again serves as a scattering potential for the fluxons, leading to a delay in the fluxon propagation time. This property can, in principle, be used for a measurement of the qubit at the symmetry point even for weak qubit-JTL coupling.

For a realistic assessment of the feasibility for the proposed measurement schemes, we need to consider the major sources of errors. One of them is thermal noise in the JTL, as

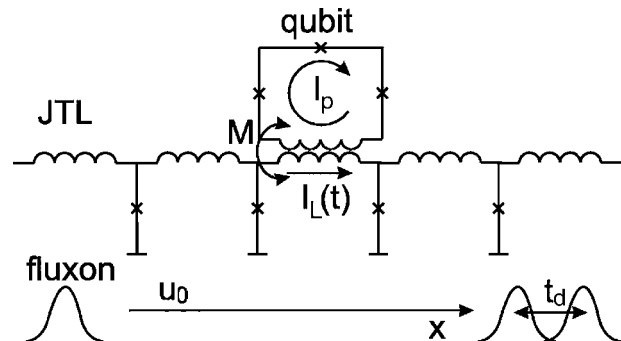


FIG. 1. Setup for the readout of the persistent current qubit based on the delay time of a soliton in the Josephson transmission line (JTL).

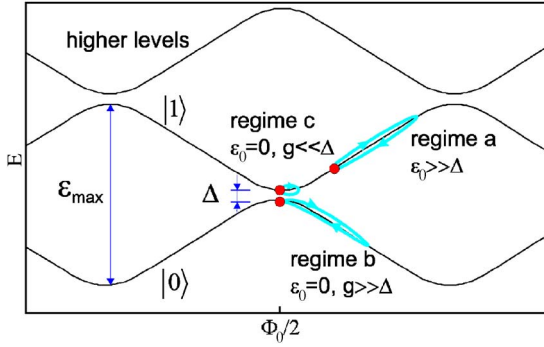


FIG. 2. (Color online) Energy diagram of the qubit energy levels as a function of the external magnetic flux in the qubit loop. The considered measurement schemes are shown as follows: (a) The qubit is kept away from the symmetry point, (b) the qubit is initially prepared at the symmetry point, but the approaching soliton pushes the qubit far from the symmetry point, and (c) the qubit remains near the symmetry point all the time. Here dots denote the working points of the qubit with no solitons in the JTL, the lines show adiabatic shifts of the working points due to magnetic flux induced in the qubit loop by a passing soliton, Δ and ϵ_0 are the tunneling amplitude and energy bias between the two persistent current states of the qubit, and g is the qubit-JTL coupling strength.

a result of which fluxons experience fluctuations in their velocity, which lead to an uncertainty (jitter) in the propagation time. In order to distinguish different eigenstates of the qubit, the induced delay time should exceed this time jitter. Another source of errors are nonadiabatic transitions of the qubit caused by the moving fluxons. This back-action effect of the JTL on the qubit needs to be taken into account if the qubit is measured at the symmetry point. Still another source of errors are intrinsic relaxation processes of the qubit due to noise not related to the JTL. The relaxation destroys the state of the qubit to be measured and should be much slower than the measurement time. Finally, in order to be detectable, the delay times should exceed the time resolution of the RSFQ detector used for delay time measurement.

Our calculations show that for suitable JTL parameters the induced delay times well exceed the time resolution of the RSFQ detector. For strong qubit-JTL coupling, the qubit measurement by a single fluxon at the symmetry point, as well as far from it, can be performed with an accuracy of 70%–90% for experimentally accessible parameters. For high velocities of the fluxon, the measurement efficiency is mostly limited by the jitter and, if the qubit is at the symmetry point, by Landau-Zener transitions. For low velocities, the intrinsic relaxation of the qubit may be important. To improve the accuracy, one has to use many fluxons for the measurement. If one optimizes the fluxon velocity and number, the qubit can be measured with accuracy reaching 99% far from the symmetry point and above 90% at the symmetry point for strong qubit-JTL coupling. The measurement time remains approximately 4 ns for both cases. For weak qubit-JTL coupling, the qubit prepared at the symmetry point stays there during the whole measurement. In this case, the measurement of the qubit is not feasible for standard JTL parameters.

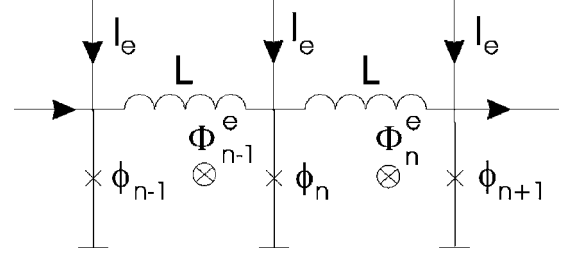


FIG. 3. Two elementary cells of the discrete JTL.

II. MODEL

We focus on the readout of a persistent current qubit^{4,5} via its coupling to solitons in a JTL in a setup shown in Fig. 1. The qubit consists of a superconducting loop with three Josephson junctions and is inductively coupled to the JTL. The Hamiltonian of the total system is

$$H = H_{qb} + H_{JTL} + H_I, \quad (1)$$

where H_{qb} describes the qubit, H_{JTL} the JTL, and H_I the qubit-JTL coupling.

On the basis of the two lowest persistent current states, $|0\rangle$, $|1\rangle$, corresponding to currents $\pm I_p$ circulating in the qubit loop in opposite directions, the qubit Hamiltonian can be expressed in terms of Pauli matrices,⁵

$$H_{qb} = -\frac{\epsilon_0}{2} \sigma_z - \frac{\Delta}{2} \sigma_x. \quad (2)$$

The tunneling amplitude Δ , leading to transitions between both states, is fixed by the experimental setup. The energy bias ϵ_0 between the two persistent current states depends on the deviation of the external magnetic flux Φ in the loop from the symmetry point,

$$\epsilon_0 = 2I_p(\Phi - \Phi_0/2), \quad (3)$$

where Φ_0 is the magnetic flux quantum.

In the absence of dissipation, the Hamiltonian of the discrete JTL, shown in Fig. 3, in vanishing external magnetic field can be expressed in terms of the charges q_n and the phase differences ϕ_n of the n th Josephson junctions

$$H_{JTL} = \sum_{n=1}^N \left[\frac{q_n^2}{2C} + E_J(1 - \cos \phi_n) + \left(\frac{\Phi_0}{2\pi} \right)^2 \frac{(\phi_{n+1} - \phi_n)^2}{2L} - \frac{\hbar I_e}{2e} \phi_n \right]. \quad (4)$$

Here, N is the total number of junctions in the JTL, which are assumed to be equal, C is the capacitance, and $E_J = \hbar I_e / 2e$ is the Josephson energy of the junction, with I_e being the junction critical current. The inductance of each cell of the JTL is denoted by L , and I_e is the bias current supplied externally to each junction.

The dimensions of the qubit are much smaller than the length a of a unit cell of the JTL. Therefore, one can assume that the qubit is inductively connected only to one cell of the JTL denoted by label m . The corresponding mutual inductance is $M = k\sqrt{L_{qb}L}$, where L_{qb} is the inductance of the qubit

loop and k is the coefficient of coupling. Thus the Hamiltonian of the qubit-JTL interaction in the linear-response regime is given by

$$H_I = \sigma_z M I_p I_L = -\frac{g}{2} \sigma_z (\phi_m - \phi_{m+1}), \quad (5)$$

where I_L is the electrical current in the inductance of the m th JTL cell and $g = 2I_p M \Phi_0 / (2\pi L)$ is the effective qubit-JTL coupling strength.

The classical dynamics of the uniform, discrete, dissipative JTL is governed by Kirchhoff circuit equations,⁶ which lead to a system of N discrete sine-Gordon equations

$$\begin{aligned} \frac{\ddot{\phi}_n}{\omega_p^2} + \frac{\dot{\phi}_n}{\omega_c} + \sin \phi_n &= \frac{I_e}{I_c} + \frac{1}{L} (\Phi_{n-1}^e - \Phi_n^e) \\ &\quad - \frac{\Phi_0}{2\pi L I_c} (\phi_{n-1} - 2\phi_n + \phi_{n+1}). \end{aligned} \quad (6)$$

Here, $\omega_p = (2eI_c / \hbar C)^{1/2}$ is the plasma frequency of the junction, $\omega_c = 2eI_c / \hbar G_N$ is the junction characteristic frequency, with G_N being the normal conductance of the junction determining the dissipation in the system, and Φ_n^e is the external magnetic flux in the n th cell induced by the qubit.

For low inductances, $L I_c \ll \Phi_0$, and weak external magnetic fields, $\Phi_n^e \ll \Phi_0$, the phases ϕ_n of the neighboring junctions are close to each other, and we can rewrite Eq. (6) in dimensionless differential form,

$$\ddot{\phi} - \phi_{xx} + \sin \phi = j_e - \alpha \dot{\phi} + f^{qb}(\phi, x). \quad (7)$$

Here, the time t and continuous space variable x are measured in units of the inverse plasma frequency ω_p^{-1} and the Josephson penetration depth $\lambda_J = a[\Phi_0 / (2\pi L I_c)]^{1/2}$, respectively, and the phase difference $\phi(x)$ is a function of x . Furthermore, $\alpha = \omega_p / \omega_c$ is the dimensionless dissipation strength and $f^{qb}(\phi, x)$ is the perturbation induced by the qubit.

In the following sections, we will show that far from the symmetry point, $\epsilon_0 \gg \Delta$, the perturbation created by the magnetic flux due to the qubit can be expressed as

$$f_{\text{flux}}^{qb}(\phi, x) = \pm 2\pi (M I_p / \Phi_0) \delta'(x), \quad (8)$$

where the different signs, \pm , correspond to the two persistent current states $|0\rangle$ and $|1\rangle$ of the qubit, respectively, and $\delta'(x)$ is a derivative of the delta function.

For a qubit remaining at the symmetry point, $\epsilon_0 = 0$, $g \ll \Delta$, we obtain an inductive-type interaction, and the perturbation is given by

$$f_{\text{ind}}^{qb}(\phi, x) = \pm \frac{4I_p^2 M^2 / \Delta}{L \lambda_J a} \frac{\partial}{\partial x} [\delta(x) \phi_x]. \quad (9)$$

Here, the different signs, \pm , correspond to the energy eigenstates of the qubit at the symmetry point, $|\pm\rangle = (1/\sqrt{2}) \times (|0\rangle \pm |1\rangle)$.

In the limit $\alpha = j_e = f^{qb} = 0$, the exact soliton solution of Eq. (7) has the form

$$\phi_0(x, t) = 4 \tan^{-1} \left\{ \exp \left[\pm \frac{x - ut - x_0}{(1 - u^2)^{1/2}} \right] \right\}, \quad (10)$$

where the positive (negative) sign corresponds to a fluxon (antifluxon), x_0 is the initial position of the soliton, and u its velocity, which can take values between -1 and 1 . To analyze the fluxon dynamics in the JTL following from Eq. (7) in the general case, we make use of the collective coordinate perturbation theory developed by McLoughlin and Scott.⁷ It is based on the assumption that j_e , $\alpha \dot{\phi}$, $f^{qb}(\phi, x) \ll 1$, which allows writing the fluxon solution in the form

$$\phi_0(x, t; u, X) = 4 \tan^{-1} \left[\exp \left(\frac{x - X(t)}{[1 - u^2(t)]^{1/2}} \right) \right]. \quad (11)$$

Here, $u(t)$ and $X(t)$ can be regarded as the time-dependent fluxon velocity and the coordinate of its center, respectively. For simplicity, we consider here the case where only one fluxon is present in the system.

Without coupling to the qubit, $f^{qb} = 0$, the stationary velocity of a fluxon can be derived from the power balance equation⁷ and is given by

$$u_0 = \left[1 + \left(\frac{4\alpha}{\pi j_e} \right)^2 \right]^{-1/2}. \quad (12)$$

When the qubit is coupled to the JTL, for arbitrary form of the perturbation $f^{qb}(\phi, x)$, the variation parameters $X(t)$ and $u(t)$ obey the differential equations⁷

$$\begin{aligned} \frac{du}{dt} &= \frac{1}{4} \pi j_e (1 - u^2)^{3/2} - \alpha u (1 - u^2) \\ &\quad - \frac{1}{4} (1 - u^2) \int_{-\infty}^{\infty} f^{qb}(\phi_0(\Theta)) \text{sech } \Theta dx, \end{aligned} \quad (13)$$

$$\frac{dX}{dt} = u - \frac{1}{4} u (1 - u^2)^{1/2} \int_{-\infty}^{\infty} f^{qb}(\phi_0(\Theta)) \Theta \text{sech } \Theta dx, \quad (14)$$

where $\Theta = [x - X(t)] / (1 - u^2)^{1/2}$. In the following section, Eqs. (13) and (14) will be solved for both forms of the qubit perturbation f^{qb} given in Eq. (8) or (9).

III. DELAY TIMES

A. Qubit far from the symmetry point

We first consider the situation where the qubit is prepared far from the symmetry point, $\epsilon_0 \gg \Delta$. In this case, the eigenstates of the qubit are the persistent current states, $|0\rangle$ and $|1\rangle$. For each of them, a magnetic flux $\pm M I_p$ penetrates the cell of the JTL, which is inductively coupled to the qubit. If the size of the qubit is much less than the Josephson penetration depth λ_J , the external magnetic flux in the JTL can be written as

$$\Phi^e(x) = \pm M I_p \theta(x), \quad (15)$$

where $\theta(x)$ is the step function and we assumed the qubit to be located at $x = 0$. The corresponding perturbation term in the equation of motion (7) can be written as

TABLE I. Parameters of the JTL and the persistent current qubit. For both variants of the JTL we take $\omega_p/2\pi=24$ GHz, critical current density $J_c=30$ A/cm², and junction specific capacitance $c=42$ fF/ μm^2 . The diameter of the junction is denoted by d .

Parameters of JTL ^a					Qubit-JTL coupling, k		Parameters of persistent current qubit ^b				
I_c (μA)	d (μm)	λ_J (a)	L (pH)	C (fF)	$g \gg \Delta$	$g \ll \Delta$	$\Delta/2\pi$ (GHz)	$\epsilon_{\max}/2\pi$ (GHz)	L_{qb} (pH)	I_p (nA)	
0.6	1.6	2	137	84	0.96	0.05	5.5	55	5	300	
2	2.9	2	41	297	0.53	0.025					

^aReferences 1 and 8.

^bReference 9.

$$f_{\text{flux}}^{qb}(\phi, x) = \pm \phi_1^q \delta'(x), \quad (16)$$

where $\phi_1^q = 2\pi M I_p / \Phi_0$ is the dimensionless qubit-JTL coupling. A thorough experimental and theoretical study of the fluxon dynamics described by the sine-Gordon equation with delta-function terms was performed in Refs. 10 and 11 for long annular Josephson junctions. The effect of discreteness of the JTL on fluxon propagation was studied in Refs. 12 and 13. The propagation of the charge soliton in one-dimensional array of serially coupled Josephson junction was studied in Ref. 14.

The dimensionless coupling ϕ_1^q depends linearly on the mutual inductance M , which for typical experimental conditions is much lower than 1. Increasing the coupling coefficient k between the qubit loop and the JTL cell enhances the influence of the qubit on the fluxon dynamics in the JTL but, at the same time, increases the back action of the fluxon on the qubit. In particular, the fluxon induces a magnetic flux in the qubit loop, which shifts the working point of the qubit. The persistent current qubit is only well defined when the external flux in the qubit loop is close to the symmetry point $\Phi_0/2$. For larger values of the external magnetic flux, the form of qubit-JTL perturbation (16) is not valid and a more elaborate model should be used. Moreover, large deviations of the working point can lead to nonadiabatic transitions to higher levels, which also makes the two-level model invalid. In the following, we require $\max\{M I_p I_L\} < \epsilon_{\max}/2$, where ϵ_{\max} is the maximum value of the energy bias between two persistent current states for which our system can still be regarded as the persistent current qubit. This condition translates to the following limitation for the dimensionless coupling:

$$\phi_1^q < \frac{\epsilon_{\max}}{\Phi_0^2 a I (\pi^2 L \lambda_J)}, \quad (17)$$

and for the coupling coefficient $k = M / \sqrt{L L_{qb}}$,

$$k < \frac{\pi}{2} \left(\frac{\epsilon_{\max} \lambda_J}{I_p \Phi_0 a} \right) \left(\frac{L}{L_{qb}} \right)^{1/2}. \quad (18)$$

The right-hand side of Eq. (17) is the ratio between the qubit energy splitting and the magnetic energy of a fluxon $\Phi_0^2 a I / (\pi^2 L \lambda_J)$. It demonstrates that the efficiency of the measurement is low if the magnetic energy of a soliton is much higher than the qubit energy, because one needs to decrease the coupling coefficient k according to Eq. (18).

The magnetic energy of a soliton in the JTL can be reduced by decreasing the critical current I_c of the junctions. We evaluate the delay times for two specific values of the critical current, $I_c=0.6$ μA and $I_c=2$ μA . Given these values, the cell inductance L has to be chosen appropriately to yield suitable values of the Josephson penetration depth λ_J . This length should be large to minimize effects of the discreteness of the JTL, $\lambda_J \geq 2a$. On the other hand, it is useful to have λ_J as small as possible to decrease the magnetic energy of a fluxon and to keep the number of Josephson junctions in the JTL within practical limits. Based on these considerations,¹ we choose $\lambda_J=2a$. The parameters of the qubit and JTL for the standard multilayer fabrication process with the lowest commercially available critical current density $J_c=30$ A/cm², which were used in the calculations, are listed in Table I.

At low critical currents of the junction, high cell inductances are needed in order to reach the required Josephson penetration depth. For standard multilayer JTL, the specific inductance per unit length can be estimated as $\kappa = \mu_0(d + 2\lambda)/b$, where μ_0 is the permeability of vacuum, d is the distance from the superconducting strip to the ground plane, λ is the superconducting penetration depth, and b is the width of the superconducting strip. For realistic parameters $d \sim 500$ nm and $\lambda \sim 100$ nm, one needs $b \sim 1$ μm to have the value of the specific inductance per unit length of the order of ~ 0.7 pH/ μm . The JTL can also be designed in such a way that the superconducting strip is located over the ground plane only partially. In this case, the inductance per unit length is approximately three times larger than the inductance over the ground plane in a typical configuration. The corresponding lengths of the elementary cells for the given specific inductance of 0.7 pH/ μm are of the order of ~ 100 μm , which can be realized in the experiment. The removal of the ground plane under the inductances simultaneously reduces the parasitic capacitance to negligible values.

From Eqs. (13)–(16), we obtain

$$\begin{aligned} \frac{du}{dt} &= \frac{1}{4} \pi j_c (1-u^2)^{3/2} - \alpha u (1-u^2) \\ &\pm \frac{1}{4} (1-u^2)^{1/2} \phi_1^q \text{sech}^2 \Theta_0 \text{sh} \Theta_0, \end{aligned} \quad (19)$$

$$\frac{dX}{dt} = u \pm \frac{1}{4} u \phi_1^q (\cosh \Theta_0 - \Theta_0 \text{sh} \Theta_0) \text{sech}^2 \Theta_0, \quad (20)$$

where $\Theta_0 = X / (1-u^2)^{1/2}$.

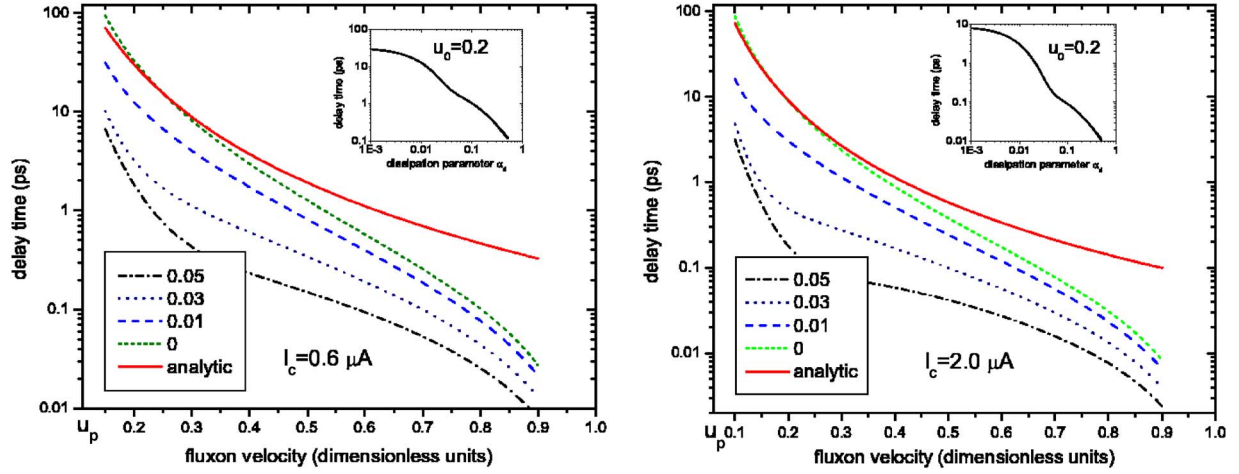


FIG. 4. (Color online) Delay time of a soliton induced by the qubit as a function of initial soliton velocity u_0 when the qubit is far from the symmetry point, $\epsilon_0 \gg \Delta$. The velocity and time are measured in units of $\lambda_J \omega_p$ and ω_p^{-1} , respectively. Four curves are obtained numerically from Eqs. (13) and (14) for different values of the dissipation strength α (shown in the legend box). The solid line shows the analytical solution (24). The parameters of the JTL and the persistent current qubit are listed in Table I. The inset shows the dependence of the delay time on the dissipation strength α for the initial soliton velocity $u_0=0.2$.

In the ballistic regime, $j_e=0$ and $\alpha=0$, we can integrate Eqs. (19) and (20) analytically¹⁵ for the qubit prepared in the eigenstates $|0\rangle$,

$$X = \pm (1 - u^2)^{1/2} \operatorname{arccch} \left[\frac{4}{\phi_1^q} \left(\sqrt{\frac{1-u^2}{1-u_0^2}} - 1 \right) \right]. \quad (21)$$

The solution for the state $|1\rangle$ is obtained by replacing ϕ_1^q with $-\phi_1^q$.

To proceed, we first consider the situation where the soliton is able to pass the potential and, therefore, we can always introduce the delay time caused by the perturbation due to the qubit as

$$t_d = |t_{|0\rangle} - t_{|1\rangle}| = 2|t_{|0\rangle} - t_0| = \frac{2}{u_0} \int_{-\infty}^{\infty} \left| \frac{u_0 - u(X)}{u(X)} \right| dX. \quad (22)$$

Here, $t_{|0\rangle}$ and $t_{|1\rangle}$ are the propagation times corresponding to the two persistent current states of the qubit, and t_0 is the value without qubit interaction. The factor 2 in Eq. (22) reflects the fact that the perturbation f_{flux}^{qb} has the same magnitude but different signs for the two persistent current states. When the velocity is only slightly perturbed by the qubit, $\epsilon_1 = (1 - u_0^2) \phi_1^q / (4u_0^2) \ll 1$, we find

$$u(\Theta_0) = u_0(1 - \epsilon_1 \operatorname{sech} \Theta_0) + o(\epsilon_1^2). \quad (23)$$

The delay time (22) can then be evaluated as

$$t_d = \frac{2\epsilon_1}{u_0^2} \int_{-\infty}^{\infty} \epsilon_1 \operatorname{sech} \left[\frac{X}{(1 - u_0^2)^{1/2}} \right] dX \approx \frac{\pi \phi_1^q}{2u_0^3}, \quad (24)$$

where the last part of the equation describes the “nonrelativistic case” $u_0 \ll 1$.

From Eq. (21), we see that for $\phi_1^q/4 > (1 - u_0^2)^{-1/2} - 1$ the soliton does not have enough kinetic energy to pass the potential barrier induced by the qubit in the state $|0\rangle$. After

approaching the qubit, the soliton will be reflected by the barrier. Due to the combination of dissipation and driving, the soliton will oscillate and eventually stop at the “pinning point,” where $u=0$ and $\dot{X}=0$. The pinning of a fluxon can also be used for the transmission detection mode of measurement, but will not be analyzed here further.

The results of a numerical evaluation of the delay times for the JTL with dissipation are presented in Fig. 4. As expected, the analytical formula (24) gives a good estimate even for intermediate values of the soliton velocity $u_p \ll u_0 \ll 1$, where u_p is the minimal possible velocity for which a fluxon is still able to pass the potential barrier created by the qubit.

Another observation is that for a fixed value of the soliton velocity u_0 the delay time decreases with increasing strength of the dissipation α . This property is displayed by Fig. 5, which shows the velocity as a function of the soliton center coordinate X for different values of α . One can see that with increasing dissipation, the fluxon velocity deviates from the dissipationless solution (13) and (14). The initial decline of the fluxon velocity becomes less effective and is also partially compensated by the following acceleration of the fluxon. The compensation is more complete the higher the dissipation, which leads to zero delay times in the limit of strong dissipation. This behavior is typical for the particle driven in viscous media and can be understood from power balance considerations. Let us consider the case when the qubit induces a positive potential barrier for a fluxon. When a fluxon is moving with stationary velocity far from the qubit, its energy gain and losses are equal. Approaching the potential barrier, the velocity of a fluxon decreases, which leads to a reduction in energy losses due to dissipation. However, the gain of energy due to driving stays on the same level. As a result, the fluxon receives an excess amount of energy, which later leads to an increase of the fluxon velocity above the initial value. Thus, we can use the dissipationless solution as an approximation for evaluating the delay times

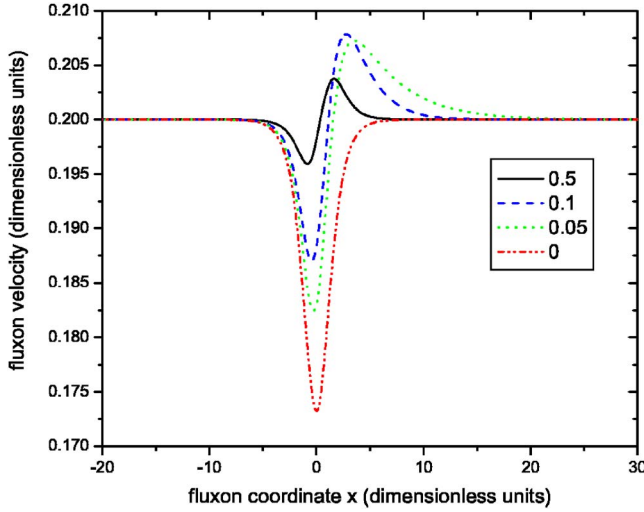


FIG. 5. (Color online) Fluxon velocity as function of its center coordinate for different values of the dissipation strength α (shown in the legend box).

of a fluxon only if $\alpha < \phi_1^q$. For $\alpha > \phi_1^q$, the delay times degrade rapidly with increasing α . We expect that the delay times can be reliably detected only if $\alpha \lesssim \phi_1^q$. This establishes another limitation to the parameters of the JTL for the case of very weak qubit-JTL coupling.

B. Qubit at the symmetry point: Strong coupling

Here, we consider the situation when the qubit is initially prepared at the symmetry point but shifted far from it by the moving fluxon. In what follows, we will show that this regime is approximately equivalent to the one when the qubit is kept far from the symmetry point all the time, and we can use the previous results for the delay time. Indeed, for typical parameters of the JTL and inductive coupling of the order of 1, we have $g \gg \Delta$, which proves that even if the qubit is initially prepared at the symmetry point, $\epsilon_0=0$, it is shifted far from it by the flux induced in the qubit loop by the moving fluxon. At the symmetry point, the persistent current in the qubit loop is zero, and the qubit induces no magnetic flux in the JTL cell, $I_L(t)=0$. As soon as the approaching fluxon shifts the qubit from the symmetry point, $2MI_p I_L(t) \sim \Delta$, the persistent current is no longer zero. The maximum value of the persistent current I_p is reached once the qubit is pushed far from the symmetry point, $2I_p M I_L(t) \gg \Delta$. When the fluxon moves away, the qubit returns to the symmetry point with zero persistent current in its loop. These considerations, of course, are valid only if the qubit was prepared in an energy eigenstate and if the shift by the fluxon occurs adiabatically. The qubit affects the fluxon dynamics only during the period of time $\sim \lambda_j/u_0$, when the fluxon is moving close to the qubit. Most of this time, the qubit is already shifted far from the symmetry point and induces the perturbation to the fluxon motion according to Eq. (8). The fast switching of the persistent current from zero to I_p and back in the initial and final stages of the qubit-JTL magnetic flux exchange yields only a small contribution to the overall delay time experienced by the fluxon. Therefore, we can use

the calculated delay times shown in Fig. 4 even if the qubit is initially prepared at the symmetry point for $g \gg \Delta$. However, we need to evaluate the probability of nonadiabatic transitions of the qubit to another eigenstate, which creates an additional source of error for the measurement. These results will be presented in Sec. IV.

C. Qubit at the symmetry point: Weak coupling

In this section, we consider the situation where the qubit is prepared initially at the symmetry point $\epsilon_0=0$ and remains nearby during the measurement. This requires that the coupling between qubit and JTL is weak and $g \ll \Delta$ to ensure that a soliton does not shift the qubit from the symmetry point significantly. As a consequence, the expectation value of the flux in the energy eigenstates of the qubit is close to zero. If the coupling term (5) varies slowly, we can treat the sum $H_{qb} + H_I$ in an adiabatic approximation and diagonalize it to obtain

$$H_{qb} + H_I = \rho_z \sqrt{\Delta^2/4 + M^2 I_p^2 I_L^2(t)} \\ \approx \frac{\Delta}{2} \rho_z + \frac{L_{eff} I_L^2(t)}{2} \rho_z = H_{qb}^{adiab} + H_I^{adiab}, \quad (25)$$

where $L_{eff} = 2I_p^2 M^2 / \Delta$. The approximation is valid if $P \ll 1$, where P is the probability of Landau-Zener transition between energy eigenstates due to time dependence of $I_L(t)$, which is calculated in the next section.

The interaction term H_I^{adiab} indicates that the qubit-JTL interaction in the adiabatic approximation is equivalent to the change of the inductance of the JTL cell, which is coupled to the qubit by the additional value of L_{eff} whose sign depends on the energy eigenstate of the qubit. This property can be used for the readout of the qubit when it is always kept at the symmetry point $\Phi = \Phi_0/2$.

The qubit-JTL interaction H_I^{adiab} leads to the following perturbation term in the sine-Gordon equation (7):

$$f_{ind}^{qb}(\phi, x) = \pm \phi_2^q \frac{\partial}{\partial x} [\delta(x) \phi_x], \quad (26)$$

where $\phi_2^q = L_{eff} a / (L \lambda_j)$ is the corresponding dimensionless qubit-JTL coupling and \pm correspond to the eigenstates $|\pm\rangle = (1/\sqrt{2})(|0\rangle \pm |1\rangle)$.

The Hamiltonian (25) is valid only for $g \ll \Delta$, which establishes the condition for the maximum possible dimensionless coupling,

$$\phi_2^q \ll \frac{\Delta/2}{\Phi_0^2 a / (\pi^2 L \lambda_j)}, \quad (27)$$

and coupling coefficient,

$$k \ll \frac{\pi}{2} \left(\frac{\Delta \lambda_j}{I_p \Phi_0 a} \right) \left(\frac{L}{L_{qb}} \right)^{1/2}. \quad (28)$$

In order to keep the qubit at the symmetry point for the chosen parameters of the qubit and the JTL (shown in

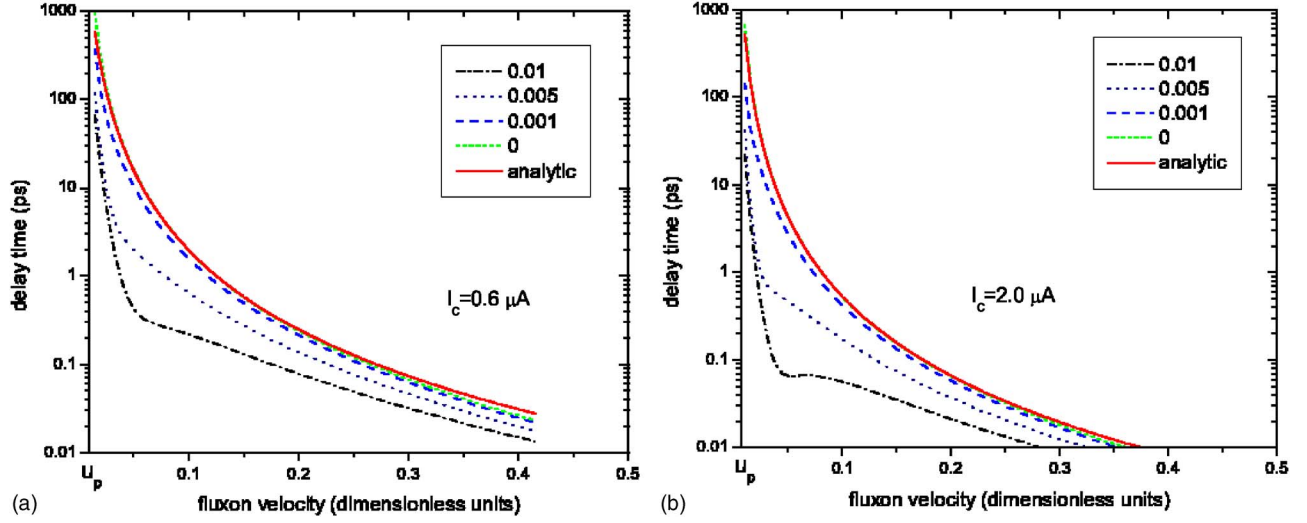


FIG. 6. (Color online) Delay time of a soliton induced by the qubit as function of the initial soliton velocity u_0 when the qubit remains at the symmetry point $\epsilon_0=0$. The velocity and time are measured in units of $\lambda_j\omega_p$ and ω_p^{-1} , respectively. Four curves are numerical solutions of Eqs. (13) and (14) for different values of the dissipation strength α (shown in the legend box). The solid curve shows the analytical solution (33). The parameters of the JTL and persistent current qubit are given in Table I. The coupling coefficient between the qubit loop and the cell of the JTL is $k=0.05$, which leads to the dimensionless coupling $\phi_2^q=3\times 10^{-4}$ in the sine-Gordon equation. The value of the coupling coefficient is reduced in order to keep the qubit at the symmetry working point all the time.

Table I), the coupling coefficient should satisfy $k\ll 0.096$ for $I_c=0.6\ \mu\text{A}$ and $k\ll 0.053$ for $I_c=2.0\ \mu\text{A}$. For the calculation, we take $k=0.05$ and $k=0.025$, which leads to $\phi_2^q=3\times 10^{-4}$ and $\phi_2^q=8\times 10^{-5}$, respectively.

From Eqs. (13), (14), and (26), we obtain

$$\frac{du}{dt} = \frac{1}{4}\pi j_e(1-u^2)^{3/2} - \alpha u(1-u^2) \pm \frac{\phi_2^q}{2}\text{sech}^2\Theta_0 \tanh\Theta_0, \quad (29)$$

$$\frac{dX}{dt} = u \pm \frac{\phi_2^q u \text{sech}^2\Theta_0}{2(1-u^2)^{1/2}}(1 - \Theta_0 \tanh\Theta_0). \quad (30)$$

For $\alpha=j_e=0$, in the nonrelativistic limit $u\ll 1$, one can evaluate for the qubit in the eigenstate $|+\rangle$

$$u^2 = u_0^2 - \frac{\phi_2^q}{2}\text{sech}^2 X \quad (31)$$

and

$$u \simeq u_0(1 - \varepsilon_2 \text{sech}^2 X) + o(\varepsilon_2^2), \quad (32)$$

where $\varepsilon_2 = \phi_2^q/(4u_0^2)$. The pinning of the fluxon occurs if $u_0^2 < \phi_2^q/2$. We can calculate the delay time according to Eq. (22) as

$$t_d = \frac{2\varepsilon_2}{u_0} \int_{-\infty}^{\infty} \text{sech}^2 X dX = \frac{\phi_2^q}{u_0^3}. \quad (33)$$

The results of the numerical evaluation of the delay times in this regime are shown in Fig. 6. For the same values of the fluxon speed, the delay times are smaller as compared to Fig. 4. However, since the pinning of a soliton occurs at slower

velocities, we can, in principle, achieve larger values of the delay times.

IV. BACK ACTION OF A FLUXON ON THE QUBIT

The back action of a fluxon on the qubit produces several effects including dephasing of the qubit in the measurement basis¹⁶ and a shift of the working point of the qubit. Dephasing, i.e., the decay of the off-diagonal elements of the density matrix of the qubit in the measurement basis, does not affect the measurement outcomes studied here¹⁷ and is not considered further.

In contrast, the shift of the working point of the qubit can potentially “destroy” the qubit and, furthermore, induce nonadiabatic transitions between the qubit states. Both processes create errors in the measurement and should be taken into account. By restricting the qubit-JTL coupling according to Eq. (18) or (28), we ensure that the system remains a persistent current qubit during the whole time of the measurement. In this section, we derive the probability of nonadiabatic transition between eigenstates of the qubit due to a passing fluxon. It should be noted that nonadiabatic transitions are a potential problem only if the qubit is initially prepared at the symmetry point. Far from the symmetry point, the Hamiltonian of the qubit (2) and the interaction Hamiltonian (5) approximately commute and nonadiabatic transitions are negligible.

In order to study nonadiabatic transitions, we assume that the qubit is initially prepared in the excited state $|-\rangle$ at the symmetry point $\epsilon_0=0$, where its unperturbed dynamics is described by the Hamiltonian $H_{qb} = -(\Delta/2)\sigma_x$. For a fluxon passing the qubit, the time-dependent qubit-JTL coupling can be written according to Eqs. (5) and (10) as

$$H_I = MI_p I_L(t) \sigma_z = - \frac{MI_p \Phi_0}{\pi L(\lambda_j/a) \sqrt{1-u_0^2}} \operatorname{sech}\left(\frac{u_0 t}{\sqrt{1-u_0^2}}\right) \sigma_z. \quad (34)$$

Here, we neglected the action of the qubit on the fluxon. The transition probability from the excited state $|-\rangle$ to the ground state $|+\rangle$ induced by one passing fluxon is then given by²⁰

$$P = MI_p (2\hbar)^{-2} \left| \frac{\sin A}{A} \int_{-\infty}^{\infty} I_L(t) e^{it\Delta/\hbar} dt \right|^2, \quad (35)$$

where $A = MI_p (2\hbar)^{-2} \int_{-\infty}^{\infty} I_L(t) dt$. After inserting Eq. (34), we obtain

$$P = \sin^2\left(\frac{I_p M \Phi_0}{L(\lambda_j/a) u_0 \hbar \omega_p}\right) \operatorname{sech}^2\left(\frac{\pi \sqrt{1-u_0^2} \Delta}{2u_0 \omega_p}\right). \quad (36)$$

We will use this result to evaluate the measurement efficiency in Sec. VII.

V. SOLITON JITTER

In order to be detected, the delay time should exceed the time fluctuations induced by thermal noise in the JTL. We can account for thermal noise by adding a stochastic term $\xi(x, t)$ to the sine-Gordon equation (7),

$$\ddot{\phi} - \phi_{xx} + \sin \phi = j_e - \alpha \phi_t - \xi(x, t). \quad (37)$$

The noise is assumed to be white with autocorrelation function

$$\langle \xi(x, t) \xi(x', t') \rangle = 16\alpha (k_B T / E_0) \delta(x - x') \delta(t - t'). \quad (38)$$

Here, $E_0 = 8(\hbar J_c \lambda_j / 2e)$ is the rest energy of a soliton, and the coefficient $16\alpha (k_B T / E_0)$ is fixed by the fluctuation-dissipation theorem.¹⁹ The noise spectral density for the fluxon velocity is given by^{18,19}

$$S_{\Delta u}(\omega) = \frac{2\alpha k_B T (1-u_0^2)^{5/2}}{E_0 \alpha^2 + \omega^2}, \quad (39)$$

where $\Delta u(t) = u(t) - u_0$. Starting from the initial condition that at $t=0$ the velocity of the fluxon is controlled and equal to u_0 , we find the velocity autocorrelation function to be given by

$$\langle \Delta u(t_1) \Delta u(t_2) \rangle = \frac{k_B T}{E_0} (1-u_0^2)^{5/2} (e^{-\alpha|t_1-t_2|} - e^{-\alpha|t_1+t_2|}). \quad (40)$$

The uncertainty in the velocity of the fluxon leads to an uncertainty of its coordinate $\Delta X(t) = \int_0^t \Delta u(t') dt'$ and propagation time $\Delta t = \Delta X / u_0$. The time jitter of the fluxon, defined as the standard deviation of the propagation time $\delta t \equiv (\langle \Delta t^2 \rangle)^{1/2}$, is then given by

$$\delta t = \left(\frac{2k_B T}{\alpha^2 E_0} \right)^{1/2} \frac{(1-u_0^2)^{5/4}}{u_0} \left[t\alpha + e^{-\alpha t} - 1 - \frac{1}{2}(1 - e^{-\alpha t})^2 \right]^{1/2}. \quad (41)$$

Limiting cases of Eq. (41) are $\delta t \propto t^{1/2}$ in the diffusive regime $\alpha t \gg 1$ and $\delta t \propto t^{3/2}$ in the ballistic regime $\alpha t \ll 1$. The time

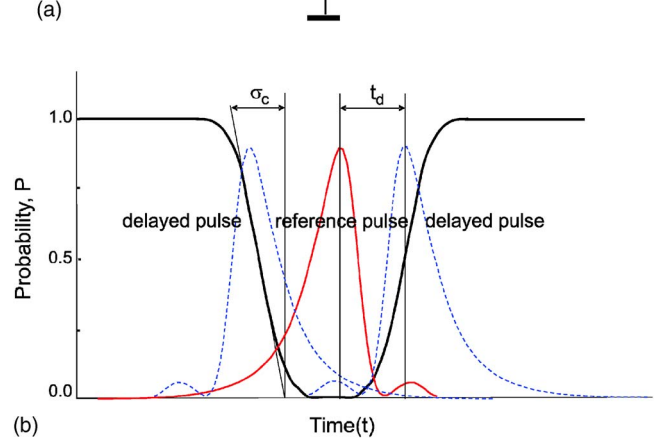
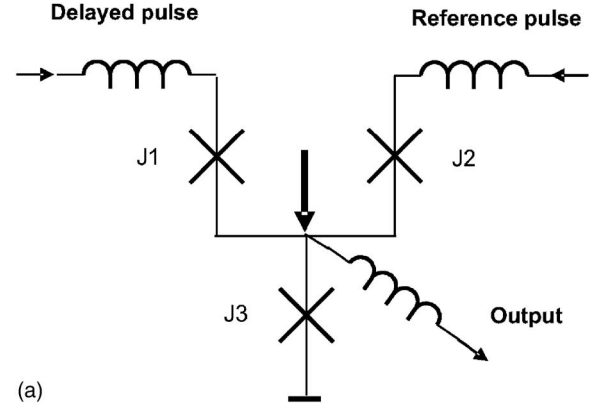


FIG. 7. (Color online) (a) Schematic of RSFQ confluence buffer and (b) the probability of double switching of output junction J3.

jitter (41) leads to further errors in the measurement procedure, which will be analyzed in Sec. VII.

VI. RSFQ DELAY DETECTOR

Before turning to a quantitative analysis of the measurement errors, we describe in this section a RSFQ delay detector that is needed to measure the time between two single flux quantum (SFQ) pulses propagating through a JTL. We first evaluate the time resolution of a single RSFQ decision gate and the time resolution of the improved detector based on a time vernier. Based on realistic parameters, we estimate the hardware complexity of the detector and discuss possible designs of the circuit presently developed experimentally.²¹

The operation of any RSFQ gate is based on the time resolution between SFQ pulses. The gates produce binary output depending on the relative time between either clock and data pulses or between two input data pulses. The simplest RSFQ gate that can be used as a decision circuit is the asynchronous OR or confluence buffer shown in Fig. 7. The figure also illustrates the operation of the confluence buffer as a time detector. A single SFQ pulse on either input produces a SFQ pulse on output. Therefore, for delayed input pulses, two output SFQ pulses are produced. In case of simultaneous arrival, the input pulses compensate each other, resulting in a SFQ pulse on output. Such behavior of the RSFQ confluence buffer is well known and has been experimentally verified many times, see, for example, Ref. 22.

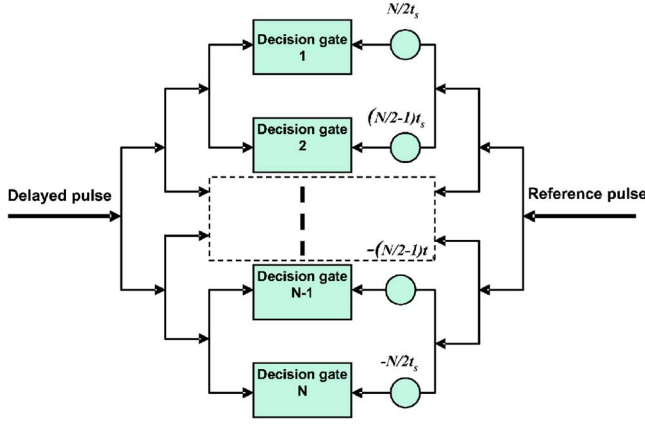


FIG. 8. (Color online) Block diagram of a RSFQ time vernier.

In general, the time resolution of any RSFQ gate is determined by the resolution of the balanced comparator formed by two junctions connected in series. In the confluence buffer, balanced comparators are formed by junctions J1, J3 or J2, J3. The probability of junction switching in the comparator obeys a normal distribution with $\sigma_c \approx 0.13t_{SFQ}$, where t_{SFQ} is the width of the SFQ pulse.^{23,24} In time units normalized to $1/\omega_p$, the width of the SFQ pulse is approximately

$$t_{SFQ} \approx 6 \frac{1}{\sqrt{\beta_c}}, \quad (42)$$

where $\sqrt{\beta_c} = \omega_c / \omega_p$ is the McCumber-Stewart parameter. The corresponding normalized one-sigma jitter of a single decision gate with $\beta_c = 2$ is

$$\sigma_c = 0.13t_{SFQ} \approx 0.78 \frac{1}{\sqrt{\beta_c}} \approx 0.55. \quad (43)$$

For a measurement error of 10^{-2} , the time resolution of a single RSFQ gate, t_r^g , is given by $4\sigma_c$ and equal to $t_r^g = 2.2$. This time resolution does not depend on the temperature since the measurement involves symmetric stochastic processes of the switching of two balanced junctions.²⁵

As is shown in Sec. III, the delay time between SFQ pulses that needs to be detected is in the range of $t_d = 0.1-5$ depending on the actual dissipation in long JTLs and the accuracy in fixing the initial fluxon velocity. In order to improve the time resolution of the RSFQ delay time detector, a vernier with N decision gates can be used,^{26,27} the block diagram of which is shown in Fig. 8. After the JTLs, both pulses propagate through the chain of splitters and arrive at a chain of N decision gates with inputs delayed in time by t_d . The operation principle of the time vernier is the same as that of a multibit analog-to-digital converter, where each bit compares the signal with a slightly shifted threshold. In accordance with the standard theory for analog-to-digital converters, the resolution improves as the square root of the number of bits.²⁸

The time resolution of the vernier is $t_r^v = t_r^g / N^{1/2}$ and the relative time difference between stages of the vernier is $t_s = t_r^g / N$. The error of time measurements depends on the ratio

between the time difference, t_s , and the jitter accumulated in the pulse paths, $\sigma_v = (2N_v)^{1/2} \sigma_J$,

$$P_{err} = \frac{1}{2} \operatorname{erfc} \left(\frac{t_s}{\sigma_v} \right). \quad (44)$$

Here, N_v is number of Josephson junctions in each pulse path and σ_J is a jitter per Josephson junction. The factor of 2 comes from the fact that there are two chains of splitters involved. The number of Josephson junctions in the splitter chain grows like $N_v = N \log N$. The single junction jitter at 4.2 K is about $\sigma_J = 0.015t_{SFQ}$ (Ref. 23) and scales as the square root of temperature and the square root of the number of shunt resistors of the junction.

Typical operating bath temperatures for the qubit experiments are about 30 mK. For process with operating frequency below 5 GHz and using cooling fins for thermalization of the hot electrons in the normal metal shunts, the effective noise temperature of the RSFQ gates can be reduced down to 80 mK for a 30 A/cm² process and to 30 mK for a 10 A/cm² process.²⁹ The temperature range between 30 and 80 mK corresponds to one-sigma jitter of $\sigma_J = 0.0012-0.0004$ for a single Josephson junction with $\beta_c = 2$.

For measurement errors of 10^{-2} , the time resolution of the RSFQ time vernier is given by $4\sigma_v$ that results in the relation for the optimum number of stages

$$\frac{4\sigma_c}{N} = 4\sqrt{2N \log N} \sigma_J. \quad (45)$$

Equation (45) gives $N=40$ and corresponding $t_r^v = 0.33$ for 30 mK (10 A/cm² process) and $N=20$ and corresponding $t_r^v = 0.5$ for 80 mK (30 A/cm² process).

VII. MEASUREMENT ERRORS

In an experimental implementation, the length L_{JTL} of the JTL is finite. For $L_{JTL} \gg \lambda_J$, the delay time of a fluxon induced by the qubit is that of the infinite JTL shown in Figs. 4 and 6. The time jitter of a fluxon at the end of the JTL is given by Eq. (41) with $t = L_{JTL}/u_0$. Due to the jitter, the propagation time of a soliton will be scattered around the average values $t_{|0\rangle}$ and $t_{|1\rangle}$ corresponding to the different energy eigenstates of the qubit $|0\rangle$ and $|1\rangle$ if the qubit is far from the symmetry point. (A similar analysis holds for distinguishing the states $|+\rangle$ and $|-\rangle$ if the qubit is at the symmetry point.) We can introduce the corresponding distribution functions $P_{|0\rangle}(t)$ and $P_{|1\rangle}(t)$ for the propagation time of a soliton, which have maxima at $t_{|0\rangle}$ and $t_{|1\rangle}$, separated by the delay time t_d and whose standard deviations are equal to the jitter δt . The overlap of the two distribution functions $P_{|0\rangle}(t)$ and $P_{|1\rangle}(t)$, shown in Fig. 9, characterizes the potential to distinguish the two eigenstates of the qubit. For a normal distribution, the area of the overlap and the associated error of the measurement are $\operatorname{erfc}[t_d/(2\sqrt{2}\delta t)]$ and $(1/2)\operatorname{erfc}[t_d/(2\sqrt{2}\delta t)]$, respectively. For the experimentally relevant case of large separation of the distribution functions, $t_d \gg \delta t$, the error can be approximated by $(\sqrt{2}\delta t/t_d) \exp \times (-t_d^2/8\delta t^2)$. The ratio of the delay time to the jitter, which

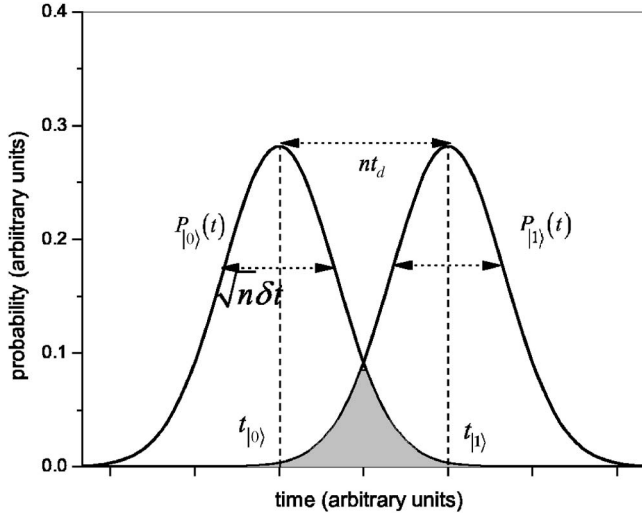


FIG. 9. Sketch of the distribution functions which describe the propagation time of a soliton. The two functions $P_{|0\rangle}(t)$ and $P_{|1\rangle}(t)$ are peaked around the average values of the propagation times $t_{|0\rangle,|1\rangle}$ corresponding to the different eigenstates of the qubit $|0\rangle$ and $|1\rangle$. The standard deviation and peak separation are given by $\sqrt{n\delta t}$ and nt_d , respectively. The overlap of the distribution functions indicates the regime where the measurement yields an error.

determines the error of measurement due to thermal fluctuations, can be estimated for a JTL with low dissipation, $\alpha \ll \phi_{1,2}^q$, according to the expressions (24), (33), and (41) as

$$\frac{t_d}{\delta t} \propto \frac{\pi\phi^q}{2u_0^{3/2}} \left(\frac{E_0\alpha}{2k_B T L_{JTL}} \right)^{1/2}. \quad (46)$$

This result suggests that in order to decrease the effect of thermal noise it is favorable to use slower fluxons. On the other hand, to avoid pinning by the qubit, we cannot choose the speed of the fluxons to be too small. According to Eq. (12), the stationary velocity of a fluxon is approximately proportional to the ratio j_e/α for $u_0 \ll 1$. For relevant dissipation strengths $\alpha \sim 0.001$, the external currents I_e supplied to each junction are in the range of 0.1–2 nA. These small values of the bias current can be experimentally applied by using rf superconducting quantum interference devices (SQUIDs) with high inductances electrically connected to each junction. The current in the rf SQUIDs is determined by an inductively coupled flux line which is easily realizable in the experiment.

For further improvement of the signal-to-noise ratio, one can use n fluxons, sending them to the JTL one after another. After n fluxon passings, the sum of the delay times and separation of the peaks of the distribution functions will scale linearly as nt_d , but the jitter will increase only as $\sqrt{n\delta t}$, and the resulting measurement error decreases according to $(1/2)\text{erfc}[\sqrt{nt_d}/(2\sqrt{2}\delta t)]$.

The qubit also experiences other sources of noise during the measurement which are not related to the JTL. Their effect can be described by two characteristic time scales: the relaxation time T_1 and the decoherence time T_2 . Decoherence, i.e., the decay of the off-diagonal elements of the density matrix of the qubit, has no effect on the measurement

TABLE II. Error of measurement by a single fluxon for $L_{JTL} = 25\lambda_J$, $T=20$ mK, $u_0=0.2$, and $\alpha=0.001$. The time of measurement is 0.8 ns.

	Variant 1	Variant 2	Variant 3
I_c (μA)	0.6	2	0.6
k	0.93	0.53	0.05
t_d (ps)	30	8.2	0.3
δt (ps)	10	5.7	10
Errors of measurement (in %)			
Jitter	7	24	50
Relaxation	0.08	0.08	0.08
LZ transitions, $\epsilon_0=0$	2	2	6.8
Total error, $\epsilon_0 \gg \Delta$	7	24	
Total error, $\epsilon_0=0$	9	26	55

outcome and is not relevant in our case. The relaxation changes the probability distribution described by the diagonal elements of the density matrix and, thus, affects the measurement. For a qubit initially prepared in the excited state, after n fluxon passings, the probability to find the qubit in the ground state is $1 - \exp[-nL_{JTL}/(u_0T_1)]$. We take this probability as the approximate (upper bound) measure of the possible error of measurement due to relaxation of the qubit.

Finally, if we measure the qubit at the symmetry point, there is an additional error associated with Landau-Zener transitions between the qubit eigenstates. Following considerations similar to the previous paragraph, we define the measure of the error due to Landau-Zener transitions as $1 - \exp(-nP)$, where the probability P is given by Eq. (36).

The efficiency of the qubit measurement by a single fluxon is given in Table II. The qubit can be measured at the symmetry point and far from it, with accuracy of approximately 90% for $I_c=0.6 \mu\text{A}$ and 75% for $I_c=2 \mu\text{A}$. One can improve the accuracy by using many fluxons. Figures 10 and 11 show the error of the measurement for the qubit initially prepared far from and at the symmetry point, respectively. The total errors of the measurements are shown on the right contour plots as a function of the number of fluxon passings and of the initial velocity of the fluxons. They are estimated as $1 - \exp[-\text{erfc}(\sqrt{nt_d}/2\sqrt{2}\delta t) - nL_{JTL}/(u_0T_1)]$ for Fig. 10 and $1 - \exp[-\text{erfc}(\sqrt{nt_d}/2\sqrt{2}\delta t) - nL_{JTL}/(u_0T_1) - nP]$ for Fig. 11. The different contributions to the total error are also plotted separately as a function of the fluxon velocity (left plots) and number of fluxon passings (insets of left plots). The nonadiabatic transitions are suppressed if the qubit is prepared far from the symmetry point; hence there is no curve related to Landau-Zener transitions in Fig. 10. One can see that for high fluxon velocities, the measurement quality is limited by the jitter and the Landau-Zener transition probability (if the qubit is at the symmetry point). For low velocities, the measurement time increases and the relaxation of the qubit becomes important. Under optimum conditions, the qubit can be measured with probability of error below 1%, far from symmetry point, and below 7% at the symmetry point, with a

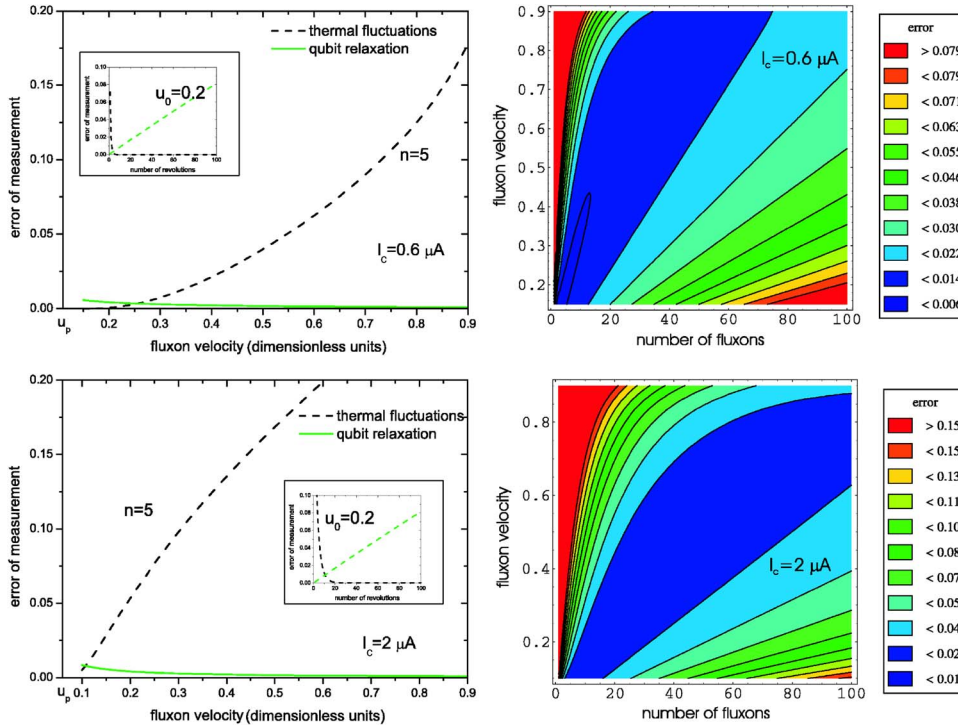


FIG. 10. (Color online) Different contributions to the measurement error for $L_J = 25\lambda_J$, $T = 20$ mK, and $\alpha = 0.001$. The upper plots correspond to $I_c = 0.6 \mu A$ and $k = 0.96$, while the lower plots correspond to $I_c = 2 \mu A$ and $k = 0.53$. The qubit is initially prepared far from the symmetry point. See text for detailed explanations.

measurement time of approximately 4 ns.

Figure 12 shows the measurement error for $L_{JTL} = 25\lambda_J$, $T = 20$ mK, $\alpha = 0.001$, and $k = 0.05$. The qubit stays at the symmetry point during the complete measurement. The coupling coefficient is chosen small to prevent a shift of the qubit from the symmetry point by the passing soliton. Thus, the influence of the qubit on the soliton is also weak, which affects the sensitivity of the measurement. From Fig. 12 it becomes clear that in order to achieve better measurements,

we need low soliton velocity and a large number of fluxon passages. As a result, the time of measurement which is required to extract the information about the qubit quantum state is comparable to the relaxation time of the qubit. This makes it impossible to efficiently measure a qubit in this regime for the chosen parameters of the JTL. A reduction of the critical current of the Josephson junctions may allow decreasing the magnetic energy of the solitons and consequently increase the coupling coefficient. In this case, the

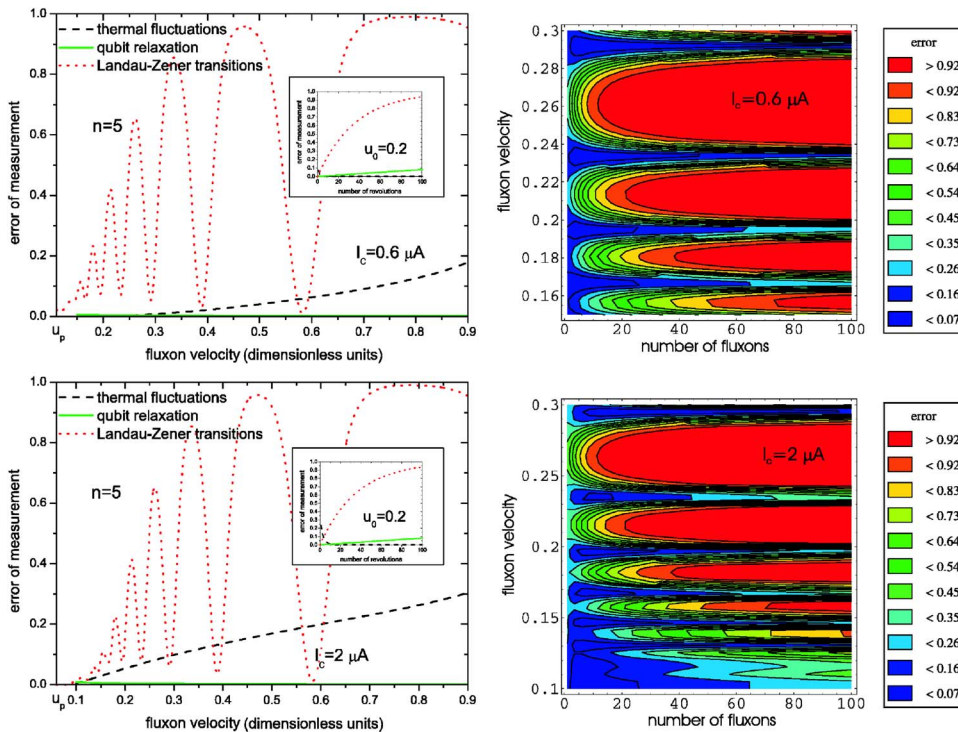


FIG. 11. (Color online) Different contributions to the measurement error for $L_{JTL} = 25\lambda_J$, $T = 20$ mK, and $\alpha = 0.001$. The upper plots correspond to $I_c = 0.6 \mu A$ and $k = 0.96$, while the lower plots correspond to $I_c = 2 \mu A$ and $k = 0.53$. The qubit is initially prepared at the symmetry point but is shifted far from it by a moving soliton. See text for detailed explanations.

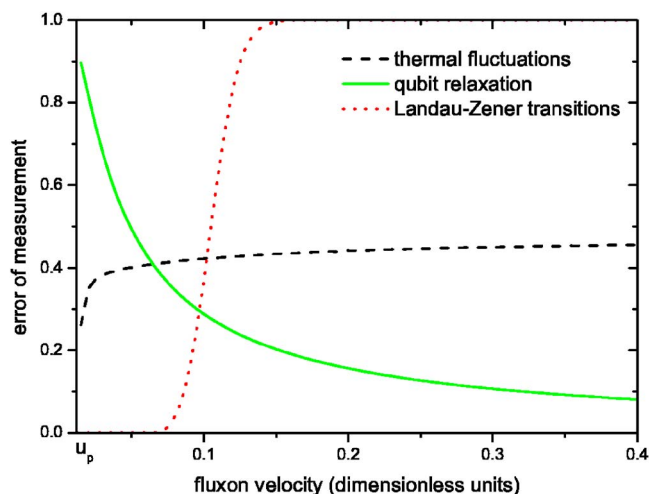


FIG. 12. (Color online) Different contributions to the error of a measurement for $L_{JTL}=25\lambda_J$, $T=20$ mK, $\alpha=0.001$, $I_c=0.6$ μA , and $k=0.05$. The qubit stays at the symmetry point during the measurement.

accuracy of the measurement will improve while the qubit will remain at the symmetry point all the time.

VIII. SUMMARY

In summary, we have analyzed the measurement process of a quantum state of a flux qubit by solitons propagating in an underdamped JTL. The coupling between the qubit and the JTL is inductive. We focused on the regime in which the information about the measured state is stored in the delay time of JTL solitons passing by (scattering from) the qubit. If the qubit is in an energy eigenstate far from the symmetry point, its persistent current induces an external magnetic flux in the JTL, which serves as a scattering potential for the JTL solitons. Two eigenstates induce different (opposite) scattering potentials, thus producing different delay times. A similar measurement mechanism works when the qubit is prepared

at the symmetry point but, due to strong coupling, each passing soliton pushes the qubit far from the symmetry point.

We have demonstrated that the delay times are longer for lower magnetic energies and velocities of the fluxons and weaker dissipation in the JTL. Since the Josephson penetration depth is fixed by the design requirement $\lambda \approx 2a$, the only possibility to reduce the magnetic energy of the soliton is to decrease the Josephson junction critical currents I_c . For low critical currents $I_c=0.6$ μA and $I_c=2.0$ μA , the delay times are in the range $t_d=0.5$ – 100 ps, which can be reliably detected by the RSFQ delay detector. The major sources of the measurement errors are the propagation time uncertainty of a fluxon due to thermal noise in the JTL and the intrinsic qubit relaxation. Nonadiabatic transitions between the energy eigenstate induced by fluxons can cause an additional error if the qubit is measured at the symmetry point. For a JTL consisting of 50 elementary cells, with dissipation strength $\alpha=0.001$, temperature $T=20$ mK, fluxon velocity $u_0=0.2$, and coupling coefficient $k \sim 1$, the measurement errors of the qubit by a single fluxon are 9% and 26% for $I_c=0.6$ μA and $I_c=2.0$ μA , respectively. In order to increase the signal-to-noise ratio, one can use many fluxons, which results in the improved accuracy of measurement exceeding 99% for the qubit far from the symmetry point and 90% at the symmetry point.

For weak qubit-JTL coupling, $k \ll 0.01$, a qubit prepared at the symmetry point stays there all the time and induces no magnetic field in the JTL. In this case, the measurement can be based on the fluxon scattered by the potential associated with the change of the effective inductance of that JTL cell which is coupled to the qubit loop. We found that a further reduction of the critical current of the Josephson junction is required for an efficient measurement in this regime.

ACKNOWLEDGMENTS

We thank C. Hutter, A. Poenicke, M. Siegel, and A. Ustinov for stimulating discussions and support. The work was supported by the EU Specific Target Project RSFQubit.

*Electronic address: arkady@tfp.uni-karlsruhe.de

¹D. V. Averin, K. Rabenstein, and V. K. Semenov, *Phys. Rev. B* **73**, 094504 (2006).

²V. K. Kaplunenko and A. V. Ustinov, *Eur. Phys. J. B* **38**, 3 (2004).

³J. Hassel, P. Helistö, H. Seppä, J. Kunert, L. Fritzsche, and H. G. Meyer, *Appl. Phys. Lett.* **89**, 182514 (2006).

⁴J. E. Mooij, T. P. Orlando, L. Levitov, L. Tian, C. H. van der Wal, and S. Lloyd, *Science* **285**, 1036 (1999).

⁵T. P. Orlando, J. E. Mooij, L. Tian, C. H. van der Wal, L. Levitov, S. Lloyd, and J. J. Mazo, *Phys. Rev. B* **60**, 15398 (1999).

⁶K. K. Likharev, *Dynamics of Josephson Junctions and Circuits* (Gordon and Breach, New York, 1996).

⁷D. W. McLaughlin and A. C. Scott, *Phys. Rev. A* **18**, 1652 (1978).

⁸A. M. Savin, J. P. Pekola, T. Holmqvist, J. Hassel, L. Grönberg, P.

Helistö, A. Kidiyarova-Shevchenko, *Appl. Phys. Lett.* **89**, 133505 (2006).

⁹A. Lupascu, C. J. P. M. Harmans, and J. E. Mooij, *Phys. Rev. B* **71**, 184506 (2005).

¹⁰A. V. Ustinov, *Appl. Phys. Lett.* **80**, 3153 (2002).

¹¹B. A. Malomed and A. V. Ustinov, *Phys. Rev. B* **69**, 064502 (2004).

¹²A. V. Ustinov, M. Cirillo, and B. A. Malomed, *Phys. Rev. B* **47**, 8357 (1993).

¹³A. V. Ustinov, M. Cirillo, B. H. Larsen, V. A. Oboznov, P. Carelli, and G. Rotoli, *Phys. Rev. B* **51**, 3081 (1995).

¹⁴Z. Hermon, E. Ben-Jacob, and G. Schön, *Phys. Rev. B* **54**, 1234 (1996).

¹⁵L. G. Aslamazov and E. V. Gurovich, *JETP Lett.* **40**, 746 (1984).

¹⁶D. V. Averin, in *Quantum Noise in Mesoscopic Physics*, edited by

- Yu. V. Nazarov (Kluwer, Dordrecht, 2003), p. 229; arXiv:cond-mat/0301524.
- ¹⁷Yu. Makhlin, G. Schön, and A. Shnirman, *Physica C* **368**, 276 (2002).
- ¹⁸E. Joergensen, V. P. Koshelets, R. Monaco, J. Mygind, M. R. Samuelsen, and M. Salerno, *Phys. Rev. Lett.* **49**, 1093 (1982).
- ¹⁹M. Salerno, E. Joergensen, and M. R. Samuelsen, *Phys. Rev. B* **30**, 2635 (1984).
- ²⁰N. Rosen and C. Zener, *Phys. Rev.* **40**, 502 (1932).
- ²¹L. Grönberg, J. Hassel, P. Helisto, M. Kiviranta, H. Seppä, M. Kulawski, T. Riekkinen, and M. Ylilampi, *Ext. Abs. ISEC*, 2005.
- ²²P. Bunyk, A. Kidiyarova-Shevchenko, and P. Litskevitch, *IEEE Trans. Appl. Supercond.* **7**, 2697 (1997).
- ²³T. Ortlep and F. H. Uhlmann, *IEEE Trans. Appl. Supercond.* (to be published).
- ²⁴T. Flippov and M. Znosko, *Ext. Abs. ISEC*, 1999.
- ²⁵Q. Herr, D. Miller, and J. Przybysz, *Supercond. Sci. Technol.* **19**, S387 (2006).
- ²⁶S. B. Kaplan, A. F. Kirichenko, O. A. Mukhanov, and S. Sarwana, *IEEE Trans. Appl. Supercond.* **11**, 978 (2001).
- ²⁷M. Terabe, A. Sekiya, T. Yamada, and A. Fujimaki, *IEEE Trans. Appl. Supercond.* (to be published).
- ²⁸P. M. Aziz, H. V. Sorensen, and J. Van Der Spiegel, *IEEE Signal Process. Mag.* **13**, 61 (1996).
- ²⁹T. Ohki, A. Savin, J. Hassel, L. Grönberg, and Anna Kidiyarova-Shevchenko, *IEEE Trans. Appl. Supercond.* (to be published).